Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-502-4493

Inclosure Material:

Metal

Overall Length:

0.340 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.187 inches

Thread Size:

0.112 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1.1 forward voltage, average and 100.0 reverse voltage, peak

Current Rating Per Characteristic:

1.10 amperes source cutoff current preset and 1.10 amperes forward current, average peak

Power Rating Per Characteristic:

7.5 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 solder stud and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0